## NSN 5961-00-424-9797

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View Online at https://aerobasegroup.com/nsn/5961-00-424-9797

## Inclosure Material:

Metal

#### **Overall Length:**

Between 0.325 inches and 0.460 inches

#### **Overall Diameter:**

0.648 inches

#### **Mounting Facility Quantity:**

1

#### **Internal Configuration:**

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### Features Provided:

#### Hermetically sealed case

#### **Overall Width Across Flats:**

0.687 inches

## Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

50.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Thread Series Designator:**

Unf

#### **Terminal Type And Quantity:**

3 tab, solder lug

#### **Specification Data:**

80131-release5228 professional/industrial association specification

#### Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

